

### NCE N-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE6042AG uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

V<sub>DS</sub> =60V,I<sub>D</sub> =42A

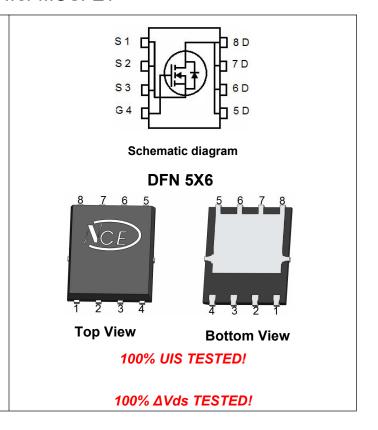
 $R_{DS(ON)}$  <14m $\Omega$  @  $V_{GS}$ =10V

 $R_{DS(ON)}$  <19m $\Omega$  @  $V_{GS}$ =4.5V

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

#### **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE6042AG	NCE6042AG	DFN5X6-8L	-	-	-

### Absolute Maximum Ratings (T<sub>c</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	60	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	42	А
Drain Current-Continuous(Tc=100℃)	I <sub>D</sub> (100°C)	29.5	Α
Pulsed Drain Current	I <sub>DM</sub>	168	Α
Maximum Power Dissipation	P <sub>D</sub>	42	W
Derating factor		0.33	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	160	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	$^{\circ}$

#### **Thermal Characteristic**

Thermal Resistance,Junction-to-Case <sup>(Note 2)</sup>	Rejc	3	°C/W

# Electrical Characteristics (T<sub>c</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	60	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=250\mu A$	1.0	1.6	2.5	V
		V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	12	14	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =20A	-	16	19	
Forward Transconductance	<b>G</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	-	15	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	Clss	\\ 20\\\\ 0\\	-	1630	-	PF
Output Capacitance	Coss	$V_{DS}$ =30V, $V_{GS}$ =0V, F=1.0MHz	-	113	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F-1.UIVIDZ	-	97	-	PF
Switching Characteristics (Note 4)				'		
Turn-on Delay Time	t <sub>d(on)</sub>		-	7.4	-	nS
Turn-on Rise Time	tr	$V_{DD}$ =30V, $R_L$ =6.7 $\Omega$	-	5.1	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =3 $\Omega$	-	28.2	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	5.5	-	nS
Total Gate Charge	Qg	N/ 001/1 00A	-	39		nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =30V,I <sub>D</sub> =20A,	-	7		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	8.5		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	42	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF =20A	-	28	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	40	-	nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD				

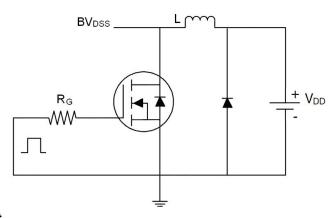
### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤  $300\mu$ s, Duty Cycle ≤ 2%.
- **4.** Guaranteed by design, not subject to production
- **5.** EAS condition : Tj=25  $^{\circ}\text{C}$  ,VDD=30V,VG=10V,L=0.5mH,Rg=25 $\Omega$

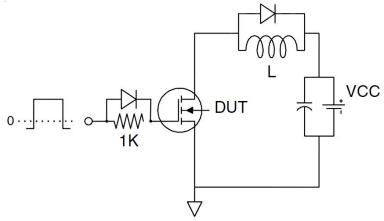


### **Test Circuit**

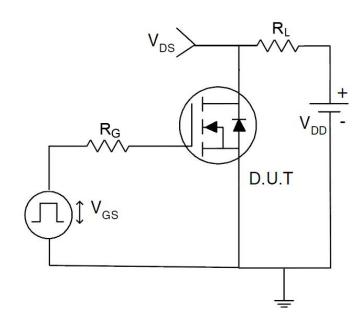
# 1) E<sub>AS</sub> test Circuit



# 2) Gate charge test Circuit

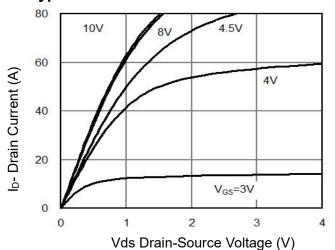


### 3) Switch Time Test Circuit

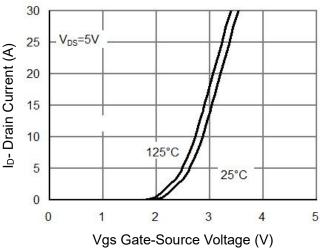




### **Typical Electrical and Thermal Characteristics (Curves)**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

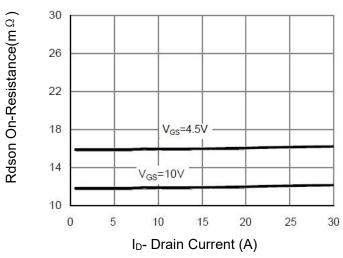
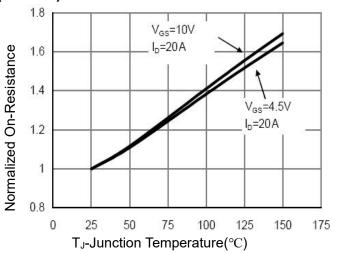


Figure 3 Rdson- Drain Current



**Figure 4 Rdson-Junction Temperature** 

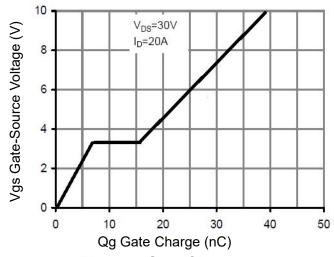


Figure 5 Gate Charge

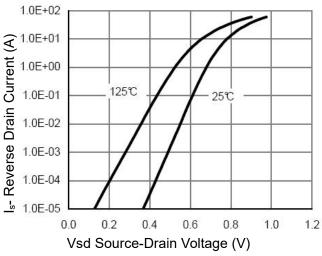
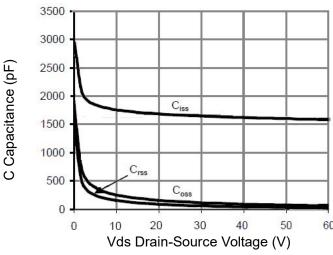


Figure 6 Source- Drain Diode Forward





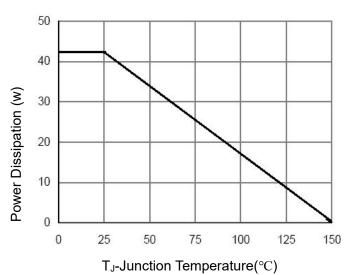
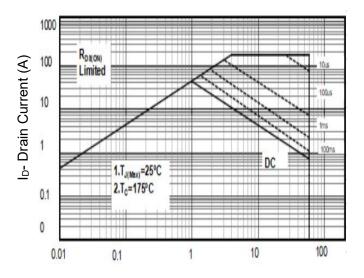
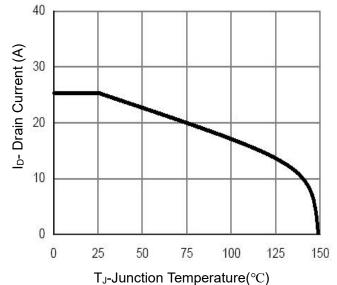


Figure 7 Capacitance vs Vds Figure 9 Power De-rating





Vds Drain-Source Voltage (V)
Figure 8 Safe Operation Area

Figure 10 Current De-rating

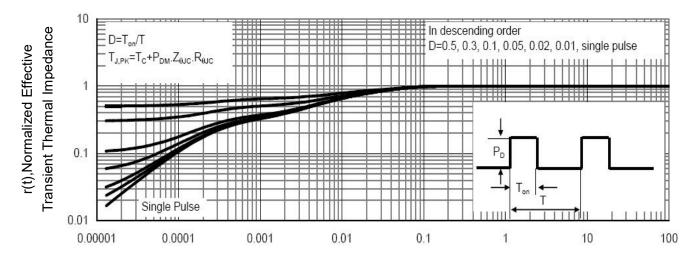
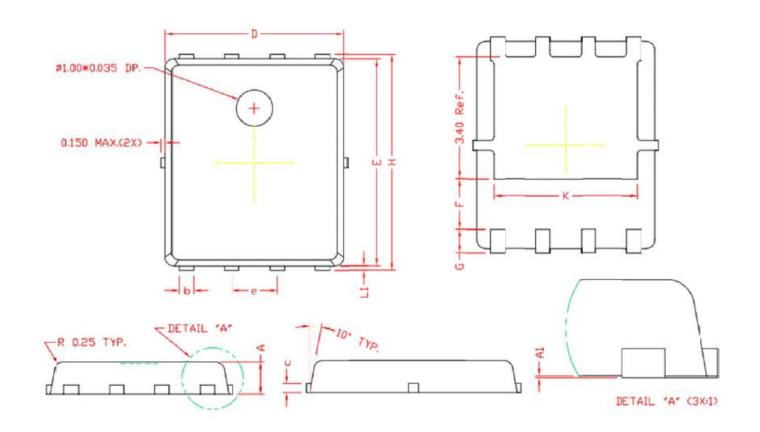


Figure 11 Normalized Maximum Transient Thermal Impedance

Square Wave Pluse Duration (sec)



# **DFN5X6-8L Package Information**



# COMMON DIMENSIONS

# (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX	
A	0.80	0.90	1.00	
A1	0.00	0.03	0.05	
b	0.35	0.42	0.49	
С	0. 254 REF.			
D	4.90	5.00	5. 10	
F	1. 40 REF.			
E	5.70	5.80	5. 90	
е	1. 27 BSC.			
Н	5.95	6.08	6. 20	
L1	0.10	0.14	0.18	
G	0.60 REF.			
K	4.00 REF.			

### http://www.ncepower.com

# NCE6042AG

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